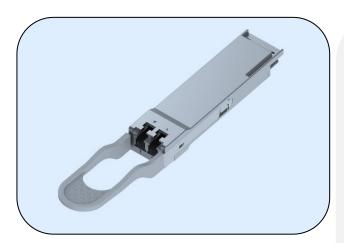


XQS319-40LY

QSFP28 4WDM 40 km Optical Transceiver Module



Applications

- IEEE 802.3ba 100GBASE ER4 Links
- Client-side 100G interconnections

Features

- 4 channels full-duplex transceiver modules
- Supports data rate up to 103.1 Gb/s
- Supports QSFP28 4WDM 40 km MSA
- 4 x 25 Gb/s DFB-based LAN-WDM Cooling transmitter
- 4 channels APD ROSA
- Internal CDR circuits on both receiver and transmitter channels
- Low power consumption < 3.8 W
- Hot Pluggable QSFP form factor
- Up to 30 km reach for G.652 SMF without FEC
- Up to 40 km reach for G.652 SMF with FEC
- Duplex LC receptacles
- Operating case temperature: 0°C to 70°C
- 3.3 power supply voltage
- RoHS compliant and lead free

Description

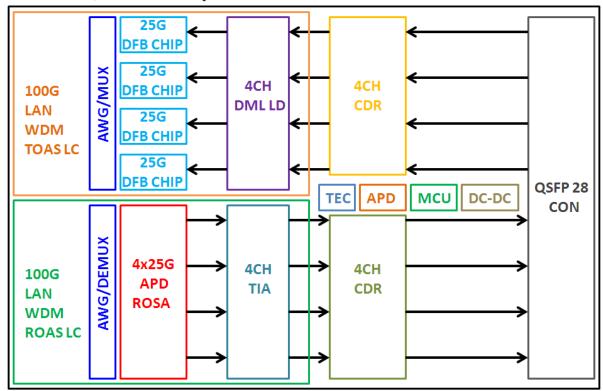
This product is a 100Gb/s transceiver module designed for optical communication applications compliant to QSFP28 4WDM 40 km MSA standard. The module converts 4 input channels of 25 Gb/s electrical data to 4 channels of LAN WDM optical signals and then multiplexes them into a single channel for 100Gb/s optical transmission. Reversely on the receiver side, the module de-multiplexes a 100 Gb/s optical input into 4 channels of LAN WDM optical signals and then converts them to 4 output channels of electrical data.

The central wavelengths of the 4 LAN WDM channels are 1295.56, 1300.05, 1304.58 and 1309.14 nm as members of the LAN WDM wavelength grid defined in IEEE 802.3ba. The high performance cooled LAN WDM DFB transmitters and high sensitivity APD receivers provide superior performance for 100Gigabit Ethernet applications up to 30 km links without FEC and up to 40 km links with FEC interconnections.

The product is designed with form factor, optical/electrical connection and digital diagnostic interface according to the QSFP+ Multi-Source Agreement (MSA). It has been designed to meet the harshest external operating conditions including temperature, humidity and EMI interference.



QSFP28 ER4/4WDM 40km CIRCUIT STRUCTURE



Absolute Maximum Ratings

Parameters	Symbol	Min.	Max.	Unit
Power Supply Voltage	V_{CC}	-0.3	3.6	V
Input Voltage	V_{in}	-0.3	V _{CC} +0.3	V
Storage Temperature	T_{st}	-20	85	°C
Operating Case Temperature	T_{op}	0	70	°C
Humidity (non-condensing)	Rh	5	85	%
Damage Threshold, Each Lane	TH	5.5		dBm

Recommended Operating Conditions

Parameter	Symbol	Min.	Typical	Max.	Unit
Supply Voltage	Vcc	3.13	3.3	3.47	V
Operating Case temperature	Tca	0		70	°C
Data Rate Per Lane	fd		25.78125		Gbps
Humidity	Rh	5		85	%
Power Dissipation	Р			3.8	W
Link Distance with G.652	D	0.002		40	km



Electrical Specifications

Parameter	Symbol	Min	Typical	Max	Unit
Power Consumption	Р			3.5	W
Supply Current	Icc			1.06	Α
Transceiver Power-on Initialization Time				2000	ms
Transm	itter (Each	Lane)			
Single-ended Input Voltage Tolerance		-0.3		4.0	V
AC Common Mode Input Voltage Tolerance		15			mV
Differential Input Voltage		50			mVpp
Differential Input Voltage Swing	Vin			900	mVpp
Differential Input Impedance	Zin	90	100	110	Ohm
Recei	ver (Each La	ane)			
Single-ended Output Voltage		-0.3		4.0	V
AC Common Mode Output Voltage				7.5	mV
Differential Output Voltage Swing	Vout	300		850	mVpp
Differential Output Impedance	Zout	90	100	110	Ohm

Note

Power-on Initialization Time is the time from when the power supply voltages reach and remain above the minimum recommended operating supply voltages to the time when the module is fully functional.



Optical Characteristics

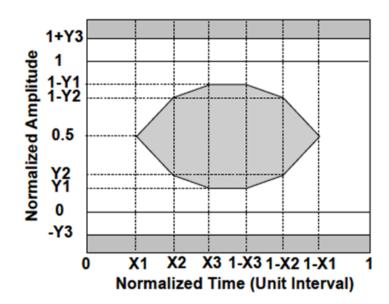
Parameter	Symbol	Min	Typical	Max	Unit	Notes
Talallecei	LO	1294.53	1295.56	1296.59	nm	Notes
	L1	1299.02	1300.05	1301.09	nm	
Lane Wavelength	L2	1303.54	1304.58	1305.63		
					nm	
	L3	1308.09	1309.14	1310.19	nm	
	Transmi				15	
SMSR	SMSR	30			dB	
Total Average Launch Power	P _T			12.5	dBm	
Average Launch Power, each Lane	P _{AVG}	-2.5		6.5	dBm	
OMA, each Lane	P _{OMA}	0.5		6.5	dBm	1
Difference in Launch Power between any Two Lanes (OMA)	Ptx,diff			3	dB	
Launch Power in OMA minus Transmitter and Dispersion Penalty (TDP), each Lane		-0.5			dBm	
TDP, each Lane	TDP			3.0	dB	
Extinction Ratio	ER	4.5			dB	
RIN ₂₀ OMA	RIN			-130	dB/Hz	
Optical Return Loss Tolerance	TOL			20	dB	
Transmitter Reflectance	R_T			-12	dB	
Eye Mask coordinates: X1, X2, X3, Y1, Y2, Y3		{0.25, 0.4,	. 0.45, 0.25,	0.28, 0.4}		2
Average Launch Power OFF Transmitter, each Lane	Poff			-30	dBm	
	Receiv	er				
Damage Threshold, each Lane	TH_d	-6			dBm	3
Average Receive Power, each Lane		-20.5		-7	dBm	
Receive Power (OMA), each Lane				-7	dBm	
Receiver Sensitivity (OMA), each						
Lane (BER = $5x10^{-5}$)	SEN1			-18.5	dBm	
Receiver Sensitivity (OMA), each Lane						
$(BER = 1x10^{-12})$	SEN1		-15	dBm		
Stressed Receiver Sensitivity (OMA), each						
Lane (BER = 5x10 ⁻⁵)				-16	dBm	4
Difference in Receive Power between any Two Lanes (OMA)	Prx,diff			3.6	dB	
LOS Assert	LOSA		-26		dBm	
LOS Deassert	LOSD		-24		dBm	
LOS Hysteresis	LOSH	0.5			dB	
Receiver Electrical 3 dB upper Cutoff				24		
Frequency, each Lane	Fc			31	GHz	



Vertical Eye Closure Penalty, each Lane		2.5	dB	5
Stressed Eye J2 Jitter, each Lane		0.33	UI	
Stressed Eye J9 Jitter, each Lane		0.48	UI	

Notes

- 1. Even if the TDP < 1 dB, the OMA min must exceed the minimum value specified here.
- 2. See Figure 4 below.
- 3. The receiver shall be able to tolerate, without damage, continuous exposure to a modulated optical input signal having this power level on one lane. The receiver does not have to operate correctly at this input power.
- 4. Measured with conformance test signal at receiver input for BER = $5x10^{-5}$.
- 5. Vertical eye closure penalty and stressed eye jitter are test conditions for measuring stressed receiver sensitivity. They are not characteristics of the receiver.





Pin Descriptions

Pin	Logic	Symbol	Name/Description	Ref.
1		GND	Module Ground	1
2	CML-I	Tx2-	Transmitter inverted data input	
3	CML-I	Tx2+	Transmitter non-inverted data input	
4		GND	Module Ground	1
5	CML-I	Tx4-	Transmitter inverted data input	
6	CML-I	Tx4+	Transmitter non-inverted data input	
7		GND	Module Ground	1
8	LVTTL-I	MODSEIL	Module Select	2
9	LVTTL-I	ResetL	Module Reset	2
10		VCCRx	+3.3v Receiver Power Supply	
11	LVCMOS-I	SCL	2-wire Serial interface clock	2
12	LVCMOS-I/O	SDA	2-wire Serial interface data	2
13		GND	Module Ground	1
14	CML-O	RX3+	Receiver non-inverted data output	
15	CML-O	RX3-	Receiver inverted data output	
16		GND	Module Ground	1
17	CML-O	RX1+	Receiver non-inverted data output	
18	CML-O	RX1-	Receiver inverted data output	
19		GND	Module Ground	1
20		GND	Module Ground	1
21	CML-O	RX2-	Receiver inverted data output	
22	CML-O	RX2+	Receiver non-inverted data output	
23		GND	Module Ground	1
24	CML-O	RX4-	Receiver inverted data output	
25	CML-O	RX4+	Receiver non-inverted data output	
26		GND	Module Ground	1
27	LVTTL-O	ModPrsL	Module Present, internal pulled down to GND	
28	LVTTL-O	IntL	Interrupt output, should be pulled up on host board	2
29		VCCTx	+3.3v Transmitter Power Supply	
30		VCC1	+3.3v Power Supply	
31	LVTTL-I	LPMode	Low Power Mode	2
32		GND	Module Ground	1
33	CML-I	Tx3+	Transmitter non-inverted data input	
34	CML-I	Tx3-	Transmitter inverted data input	
35		GND	Module Ground	1
36	CML-I	Tx1+	Transmitter non-inverted data input	
37	CML-I	Tx1-	Transmitter inverted data input	
38		GND	Module Ground	1



Notes:

- 1. Module circuit ground is isolated from module chassis ground within the module.
- 2. Open collector; should be pulled up with 4.7k 10k ohms on host board to a voltage between 3.15Vand 3.6V.

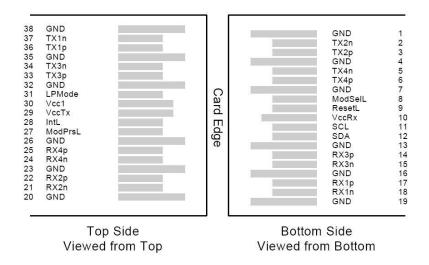


Figure 2. Electrical Pin-out Details

ModSelL Pin

The ModSelL is an input pin. When held low by the host, the module responds to 2-wire serial communication commands. The ModSelL allows the use of multiple QSFP modules on a single 2-wire interface bus. When the ModSelL is "High", the module will not respond to any 2-wire interface communication from the host.

ModSelL has an internal pull-up in the module.

ResetL Pin

Reset. LPMode_Reset has an internal pull-up in the module. A low level on the ResetL pin for longer than the minimum pulse length (t_Reset_init) initiates a complete module reset, returning all user module settings to their default state. Module Reset Assert Time (t_init) starts on the rising edge after the low level on the ResetL pin is released. During the execution of a reset (t_init) the host shall disregard all status bits until the module indicates a completion of the reset interrupt. The module indicates this by posting an IntL signal with the Data_Not_Ready bit negated. Note that on power up (including hot insertion) the module will post this completion of reset interrupt without requiring a reset.

LPMode Pin

XenOpt QSFP28 SR4 operate in the low power mode (less than 1.5 W power consumption).

This pin active high will decrease power consumption to less than 1W.

ModPrsL Pin

ModPrsL is pulled up to Vcc on the host board and grounded in the module. The ModPrsL is asserted "Low" when the module is inserted and deasserted "High" when the module is physically absent from the host connector.



IntL Pin

IntL is an output pin. When "Low", it indicates a possible module operational fault or a status critical to the host system. The host identifies the source of the interrupt by using the 2-wire serial interface. The IntL pin is an open collector output and must be pulled up to Vcc on the host board.

Power Supply Filtering

The host board should use the power supply filtering shown in Figure 3.

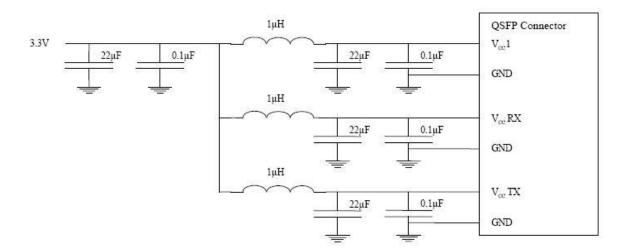


Figure 3. Host Board Power Supply Filtering



Timing for Soft Control and Status Functions

Parameter	Symbol	Max	Unit	Conditions
Initialization Time	t_init	2000	ms	Time from power on ¹ , hot plug or rising edge of Reset until the module is fully functional ²
Reset Init Assert Time	t_reset_init	2	μs	A Reset is generated by a low level longer than the minimum reset pulse time present on the ResetL pin.
Serial Bus Hardware Ready Time	t_serial	2000	ms	Time from power on ¹ until module responds to data transmission over the 2-wire serial bus
Monitor Data Ready Time	t_data	2000	ms	Time from power on ¹ to data not ready, bit 0 of Byte 2, deasserted and IntL asserted
Reset Assert Time	t_reset	2000	ms	Time from rising edge on the ResetL pin until the module is fully functional ²
LPMode Assert Time	ton_LPMode	100	μs	Time from assertion of LPMode (Vin:LPMode = Vih) until module power consumption enters lower Power Level
IntL Assert Time	ton_IntL	200	ms	Time from occurrence of condition triggering IntL until Vout:IntL = Vol
IntLDeassert Time	toff_IntL	500	μs	Time from clear on read ³ operation of associated flag until Vout:IntL = Voh. This includes deassert times for Rx LOS, Tx Fault and other flag bits.
Rx LOS Assert Time	ton_los	100	ms	Time from Rx LOS state to Rx LOS bit set and IntL asserted
Tx Fault Assert Time	ton_Txfault	200	ms	Time from Tx Fault state to Tx Fault bit set and IntL asserted
Flag Assert Time	ton_flag	200	ms	Time from occurrence of condition triggering flag to associated flag bit set and IntL asserted
Mask Assert Time	ton_mask	100	ms	Time from mask bit set ⁴ until associated IntL assertion is inhibited
Mask Deassert Time	toff_mask	100	ms	Time from mask bit cleared ⁴ until associated IntlL operation resumes
ModSelL Assert Time	ton_ModSelL	100	μs	Time from assertion of ModSelL until module responds to data transmission over the 2-wire serial bus
ModSelLDeassert Time	toff_ModSelL	100	μs	Time from deassertion of ModSelL until the module does not respond to data transmission over the 2-wire serial bus
Power_over-ride or Power-set Assert Time	ton_Pdown	100	ms	Time from P_Down bit set ⁴ until module power consumption enters lower Power Level
Power_over-ride or Power-set Deassert Time	toff_Pdown	300	ms	Time from P_Down bit cleared ⁴ until the module is fully functional3

Note:

- 1. Power on is defined as the instant when supply voltages reach and remain at or above the minimum specified value.
- $2. \ Fully \ functional \ is \ defined \ as \ IntL \ asserted \ due \ to \ data \ not \ ready \ bit, \ bit \ 0 \ byte \ 2 \ deasserted.$
- 3. Measured from falling clock edge after stop bit of read transaction.
- 4. Measured from falling clock edge after stop bit of write transaction.



Mechanical Specifications

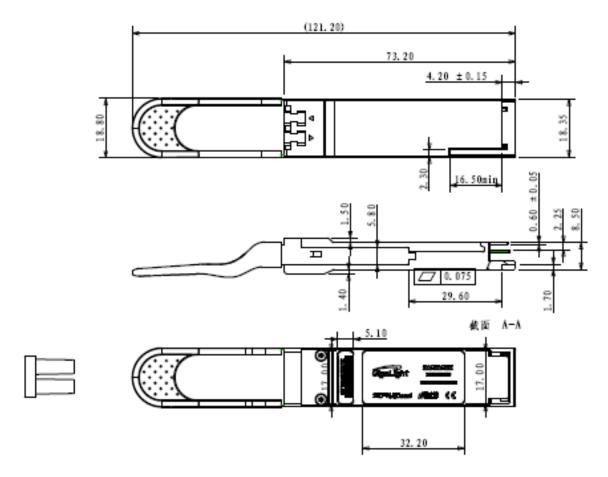


Figure 4. Mechanical Specifications

References

- 1. SFF-8436 QSFP+
- 2. Ethernet 100GBASE-ER4
- 3. QSFP28 4WDM 40 km

ESD

This transceiver is specified as ESD threshold 1kV for SFI pins and 2kV for all other electrical input pins, tested per MIL-STD-883, Method 3015.4/JESD22-A114-A (HBM). However, normal ESD precautions are still required during the handling of this module. This transceiver is shipped in ESD protective packaging. It should be removed from the packaging and handled only in an ESD protected environment.

Laser Safety

This is a Class 1 Laser Product according to IEC 60825-1:2007. This product complies with 21 CFR 1040.10 and 1040.11 except for deviations pursuant to Laser Notice No. 50, dated (June 24, 2007).

XQS319-40LY QSFP28 4WDM 40 km Transceiver

Ordering information¹

PN	Description
XQS319-40LY	QSFP28 4WDM, LAN_WDM 40 km, DDM, 0°C ~ +70°C

Notes:

Important Notice

Performance figures, data and any illustrative material provided in this data sheet are typical and must be specifically confirmed in writing by XenOpt before they become applicable to any particular order or contract. $\label{eq:contract} % \begin{center} \begin{cen$

The publication of information in this data sheet does not imply freedom from patent or other protective rights of XenOpt or others. Further details are available from any XenOpt sales representative.

To find out more, please contact



¹ Specification may change without notice. For accurate specification please contact XenOpt reseller before placing an order. The content of this document is subject to change without notice. Please specify any compatibility requirements at time of ordering. Standard MSA compatible pluggable components may not work or some function of these components may not be available in devices that require customized compatible devices. Pluggable components compatible with one type of communications equipment may not work in other type of communications equipment.